

1002MP

2 Watts, 35 Volts Pulsed Avionics at 960-1215 MHz

> CASE OUTLINE 55FW-1

GENERAL DESCRIPTION

The 1002MP is a COMMON BASE transistor capable of providing 2 Watts of pulsed RF output power in the band 960 to 1215 MHz. This transistor is specifically designed for pulsed Avionics amplifier applications. It utilizes gold metallization and low thermal resistance packaging to provide high reliability and supreme ruggedness.

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation		
Device Dissipation @ 25°C	7	W
Maximum Voltage and Curren	t	
Collector to Base Voltage (BV _{ces}) 50	V
Emitter to Base Voltage (BV _{ebo})	3.5	V
Collector Current (I _c)	250	mA
Maximum Temperatures		
Storage Temperature	40 to +150	°C
Operating Junction Temperature	+200	°C

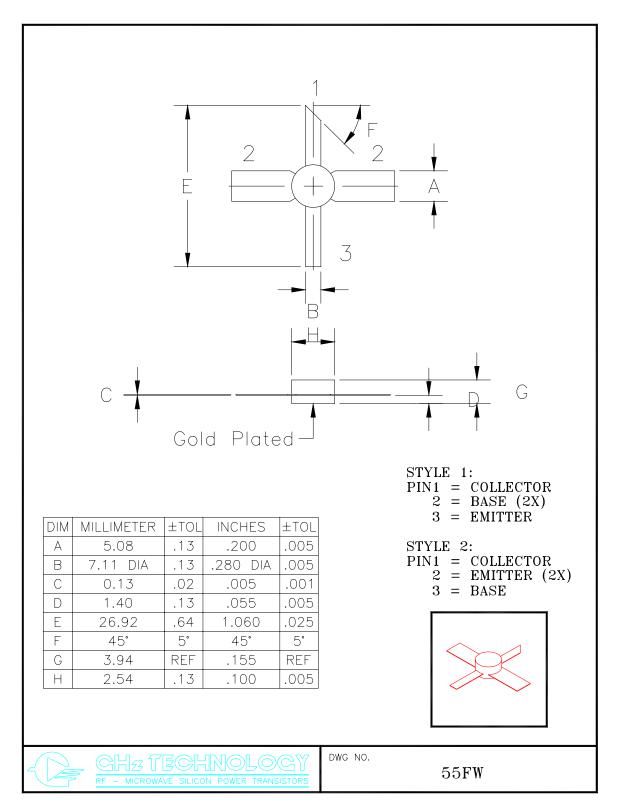
ELECTRICAL CHARACTERISTICS @ 25°C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Pout	Power Output	F = 1150 MHz	2.0	2.5		W
P _{in}	Power Input				0.3	W
Pg	Power Gain	$V_{cc} = 35$ Volts	10	11		dB
η_c	Collector Efficiency	Pulse width = $20 \ \mu s$		45		%
VSWR	Load Mismatch Tolerance	LTDF = 1%			10:1	

FUNCTIONAL CHARACTERISTICS @ 25°C

BV _{ebo}	Emitter to Base Breakdown	Ie = 50 mA	3.5			V
BV _{ces}	Collector to Emitter Breakdown	Ic = 100 mA	50			V
\mathbf{h}_{FE}	DC – Current Gain	Vce = 5V, Ic = 100 mA	20			
C _{ob}	Capacitance			2.5	5.0	pF
θjc ¹	Thermal Resistance				25	°C/W

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